

PC715V

High Sensitivity Type Photocoupler

※ Lead forming type (I type) and taping reel type (P type) are also available. (PC715VI/PC715VP)

※※ TÜV (VDE0884) approved type is also available as an option.

■ Features

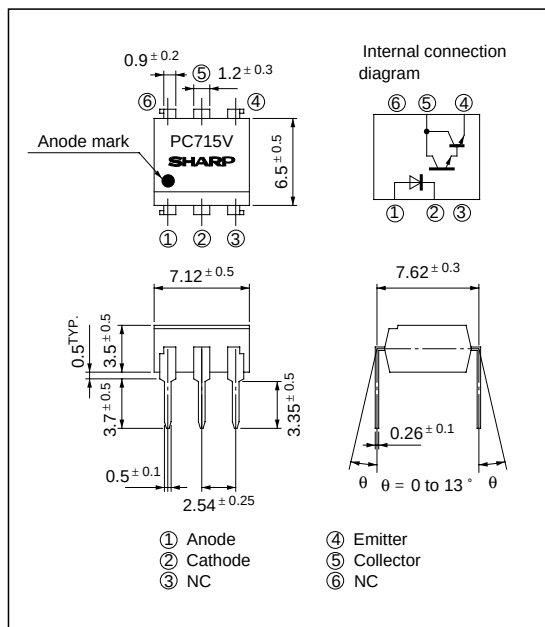
1. High current transfer ratio
(CTR : MIN. 600% at $I_F = 1\text{mA}$, $V_{CE} = 2\text{V}$)
2. High isolation voltage between input and output
($V_{iso} : 5\,000\text{V}_{rms}$)
3. Recognized by UL, file No. E64380

■ Applications

1. System appliances, measuring instruments
2. Copiers, automatic vending machines
3. Signal transmission between circuits of different potentials and impedances

■ Outline Dimensions

(Unit : mm)



■ Absolute Maximum Ratings

($T_a = 25^\circ\text{C}$)

Parameter		Symbol	Rating	Unit
Input	Forward current	I_F	50	mA
	*1 Peak forward current	I_{FM}	1	A
	Reverse voltage	V_R	6	V
	Power dissipation	P	70	mW
Output	Collector-emitter voltage	V_{CEO}	35	V
	Emitter-collector voltage	V_{ECO}	6	V
	Collector current	I_C	80	mA
	Collector power dissipation	P_C	150	mW
Total power dissipation		P_{tot}	170	mW
*2 Isolation voltage		V_{iso}	5 000	V_{rms}
Operating temperature		T_{opr}	- 25 to + 100	$^\circ\text{C}$
Storage temperature		T_{stg}	- 40 to + 125	$^\circ\text{C}$
*3 Soldering temperature		T_{sol}	260	$^\circ\text{C}$

*1 Pulse width $\leq 100\mu\text{s}$, Duty ratio : 0.001

*2 40 to 60% RH, AC for 1 minutes

*3 For 10 seconds

■ Electro-optical Characteristics

(Ta= 25°C)

Parameter			Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage		V _F	I _F = 10mA	-	1.2	1.4	V
	Peak forward voltage		V _{FM}	I _{FM} = 0.5A	-	-	3.0	V
	Reverse current		I _R	V _R = 4V	-		10	μ A
	Terminal capacitance		C _t	V = 0, f = 1kHz	-	30	250	pF
Output	Collector dark current		I _{CEO}	V _{CE} = 10V, I _F = 0	-	-	10 ⁻⁶	A
Transfer charac- teristics	Current transfer ratio		CTR	I _F = 1mA, V _{CE} = 2V	600	1 600	7 500	%
	Collector-emitter saturation voltage		V _{CE(sat)}	I _F = 20mA, I _C = 5mA	-	-	1.0	V
	Isolation resistance		R _{ISO}	DC500V, 40 to 60% RH	5 x 10 ¹⁰	10 ¹¹	-	Ω
	Floating capacitance		C _f	V = 0, f = 1MHz	-	0.6	1.0	pF
	Cut-off frequency		f _c	V _{CE} = 2V, I _C = 2mA, R _L = 100 Ω, - 3dB	-	6	-	kHz
	Response time	Rise time	t _r	V _{CE} = 2V, I _C = 10mA, R _L = 100 Ω	-	60	250	μ s
Fall time		t _f	-		53	250	μ s	

Fig. 1 Forward Current vs. Ambient Temperature

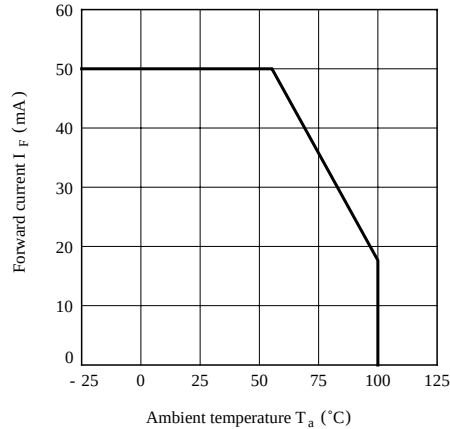


Fig. 2 Collector Power Dissipation vs. Ambient Temperature

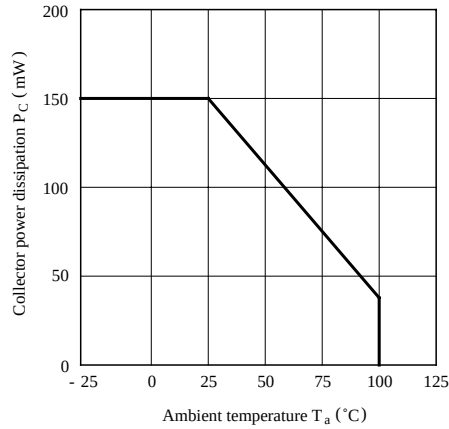


Fig. 3 Peak Forward Current vs. Duty Ratio

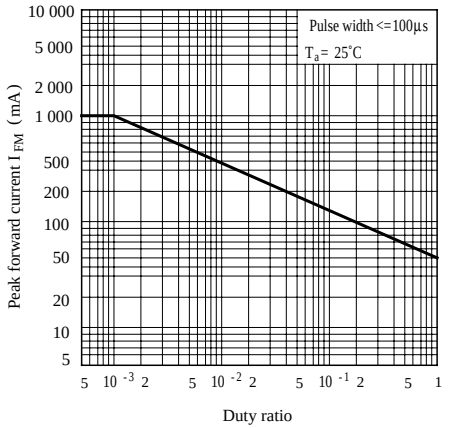


Fig. 4 Forward Current vs. Forward Voltage

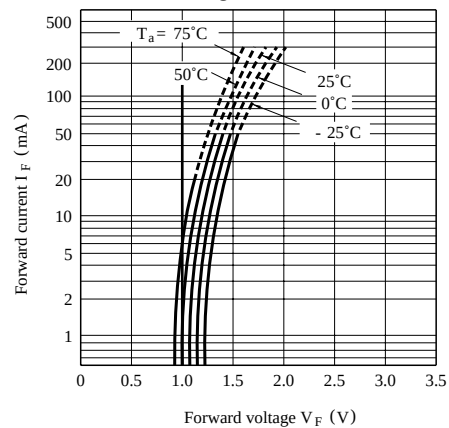


Fig. 5 Current Transfer Ratio vs. Forward Current

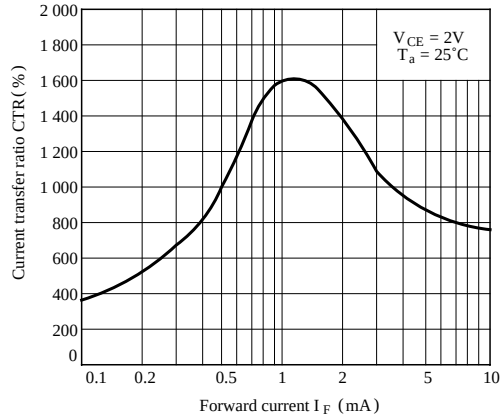


Fig. 6-a Collector Current vs. Collector-emitter Voltage

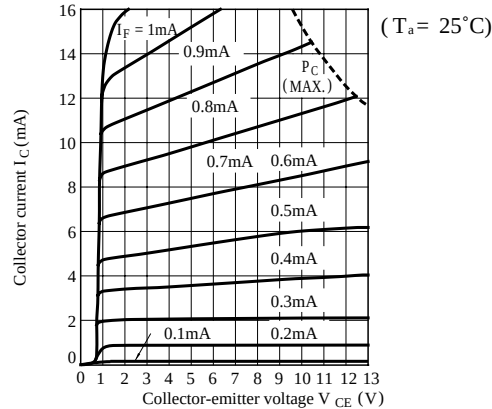


Fig. 6-b Collector Current vs. Collector-emitter Voltage

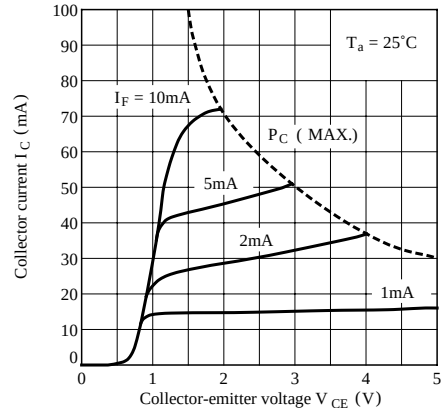


Fig. 7 Relative Current Transfer Ratio vs. Ambient Temperature

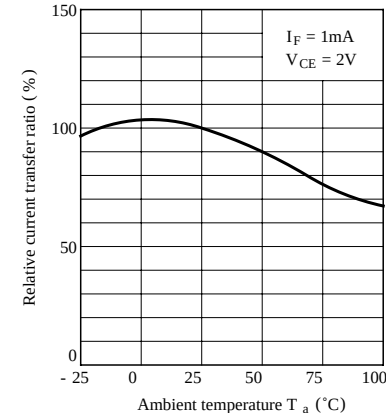


Fig. 8 Collector-emitter Saturation Voltage vs. Ambient Temperature

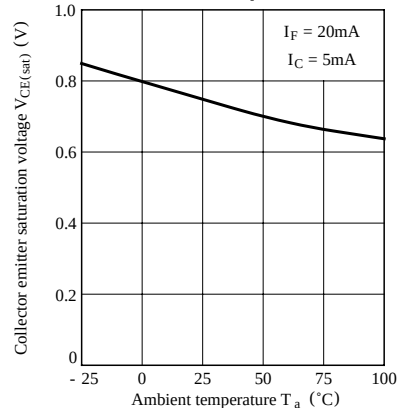


Fig. 9 Collector Dark Current vs. Ambient Temperature

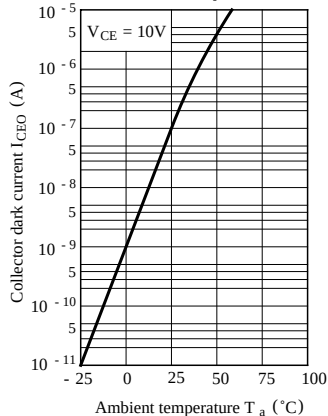


Fig.10 Response Time vs. Load Resistance

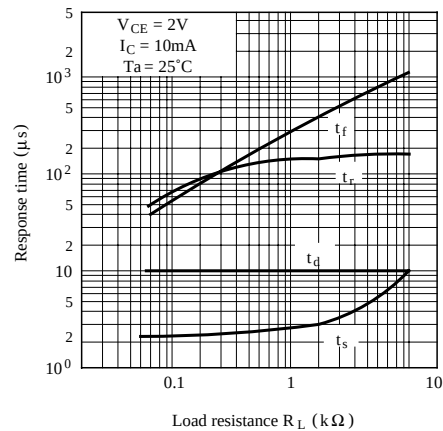
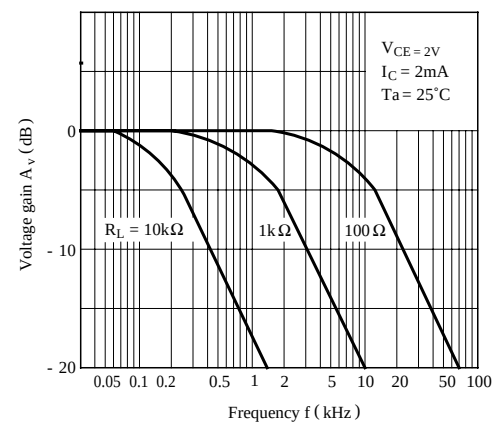
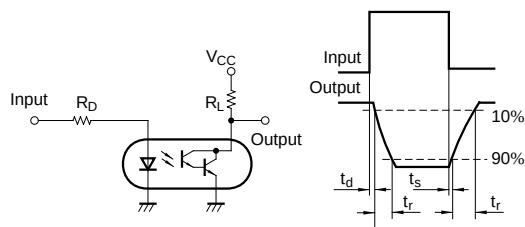


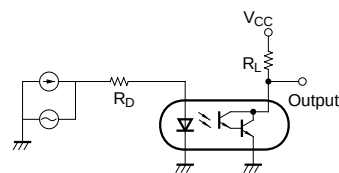
Fig.11 Frequency Response



Test Circuit for Response Time



Test Circuit for Frequency Response



●Please refer to the chapter “Precautions for Use”.